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1 Electrical ratings

Table 2. Absolute maximum ratings	Table 2.	Absolute maximum ratings
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Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage ($V_{GE} = 0$)	1200	V
I _C ⁽¹⁾	Collector current (continuous) at $T_C = 25 \ ^{\circ}C$	10	А
I _C ⁽¹⁾	Collector current (continuous) at T _C = 100 °C	5	А
I _{CP} ⁽²⁾	Pulsed collector current	10	А
I _{CL} ⁽³⁾	Turn-off latching current	10	А
V _{GE}	Gate-emitter voltage	±20	V
V _{ECR}	Emitter-collector voltage	20	V
E _{AS} ⁽⁴⁾	Single pulse avalanche energy at $T_C = 25 \ ^{\circ}C$	10	mJ
⊢AS `	Single pulse avalanche energy at $T_C = 100 \ ^{\circ}C$	7	mJ
P _{TOT}	Total dissipation at T_{C} = 25 °C	75	W
Тj	Operating junction temperature	– 55 to 150	°C

1. Calculated according to the iterative formula:

$$I_{C}(T_{C}) = \frac{T_{j(max)} - T_{C}}{R_{thj-c} \times V_{CE(sat)(max)}(T_{j(max)}, I_{C}(T_{C}))}$$

- 2. Pulse width limited by max. temperature allowed
- 3. V_{CLAMP} = 80% (V_{CES}), V_{GE} = 15 V, R_G = 10 Ω , T_J = 150 °C
- 4. $V_{CE} = 50 \text{ V}$, $I_{AV} = 3.3 \text{ A}$

Table 3. Thermal resistance

Symbol Parameter		Value	Unit
R _{thj-case}	Thermal resistance junction-case IGBT max	1.67	°C/W
R _{thj-amb} Thermal resistance junction-ambient max		100	°C/W



2 Electrical characteristics

(T_{CASE}=25 °C unless otherwise specified)

	Static cleaned characteristics						
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
V _{(BR)CES}	Collector-emitter breakdown voltage (V _{GE} = 0)	l _C = 10 mA	1200			V	
V _{CE(sat)}	Collector-emitter saturation voltage	V _{GE} = 15 V, I _C = 5 A V _{GE} = 15 V, I _C = 5 A,T _C = 125 °C		1.3 1.2	2.0		
V _{GE(th)}	Gate threshold voltage	$V_{CE} = V_{GE}$, $I_C = 250 \ \mu A$	2		5	V	
V _{GE}	Gate emitter voltage	V_{CE} = 2.5 V, I _C = 2 A, T _C = 25 ÷ 125 °C			6.5	V	
I _{CES}	Collector cut-off current (V _{GE} = 0)	V _{CE} = 900 V V _{CE} = 900 VT _C = 125 °C			50 250	μΑ μΑ	
I _{GES}	Gate-emitter leakage current (V _{CE} = 0)	$V_{GE} = \pm 20 V$			±100	nA	
9 _{fs}	Forward transconductance	$V_{CE} = 15 V_{,} I_{C} = 5 A$		5		S	
R _G	Gate resistance			4		kΩ	

Table 4. Static electrical characteristics

Table 5.	Dynamic	electrical	characteristics
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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
C _{ies} C _{oes} C _{res}	Input capacitance Output capacitance Reverse transfer capacitance	V _{CE} = 25 V, f = 1 MHz, V _{GE} = 0		430 40 7		pF pF pF

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{d(on)} t _r (di/dt) _{on}	Turn-on delay time Current rise time Turn-on current slope	$V_{CC} = 960 \text{ V}, I_C = 5A$ $R_{drive} = 1 \text{ k}\Omega, V_{GE} = 15 \text{ V},$ (see Figure 18)		690 170 39.6		ns ns A/µs
t _{d(on)} t _r (di/dt) _{on}	Turn-on delay time Current rise time Turn-on current slope	$V_{CC} = 960 \text{ V}, I_C = 5A$ $R_{drive} = 1 \text{ k}\Omega, V_{GE} = 15 \text{ V}$ $T_C = 125 \text{ °C} (see Figure 18)$		600 185 39		ns ns A/µs
t _c t _r (V _{off}) t _d (_{off}) t _f	Cross-over time Off voltage rise time Turn-off delay time Current fall time	$V_{CC} = 960 \text{ V}, I_C = 5\text{A}$ $R_{drive} = 1 \text{ k}\Omega, V_{GE} = 15 \text{ V}$ (see Figure 18)		4 2.2 12.1 1.13		μs μs μs μs
t _c t _r (V _{off}) t _d (_{off}) t _f	Cross-over time Off voltage rise time Turn-off delay time Current fall time	$V_{CC} = 960 \text{ V}, I_C = 5\text{A}$ $R_{drive} = 1 \text{ k}\Omega, V_{GE} = 15 \text{ V},$ $T_C = 125 \text{ °C} \text{ (see Figure 18)}$		5 2.2 12.1 2		μs μs μs μs

Table 6. Switching on/off (inductive load)

 Table 7.
 Switching energy (inductive load)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
E _{on} ⁽¹⁾ E _{off} ⁽²⁾ E _{ts}	Turn-on switching losses Turn-off switching losses Total switching losses	$V_{CC} = 960 \text{ V}, I_C = 5\text{A}$ $R_{drive} = 1 \text{ k}\Omega, V_{GE} = 15 \text{ V}$ (see Figure 18)		2.59 9 11.59		mJ mJ mJ
E _{on} ⁽¹⁾ E _{off} ⁽²⁾ E _{ts}	Turn-on switching losses Turn-off switching losses Total switching losses	$V_{CC} = 960 \text{ V}, I_C = 5\text{A}$ $R_{drive} = 1 \text{ k}\Omega, V_{GE} = 15 \text{ V},$ $T_C = 125 \text{ °C}$ (see Figure 18)		2.64 10.2 12.68		mJ mJ mJ

Eon is the turn-on losses when a typical diode is used in the test circuit in (see Figure 18). If the IGBT is
offered in a package with a co-pak diode, the co-pack diode is used as external diode. IGBTs & Diode are
at the same temperature (25°C and 125°C)

2. Turn-off losses include also the tail of the collector current

Table 8. Functional test

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{AS}	Unclamped inductive switching current	V_{CC} = 50 V, L = 1.8 mH T _{start} = 25 °C, R _{drive} = 1 kΩ	3.3			A



2.1 Electrical characteristics (curves)

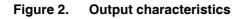


Figure 3. Transfer characteristics

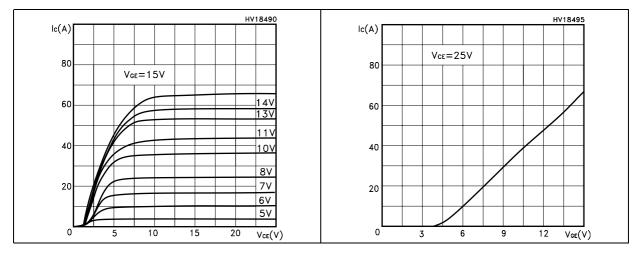
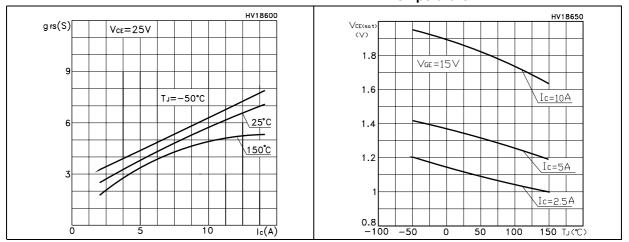
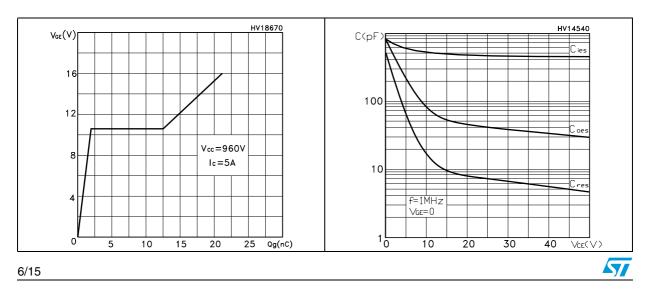




Figure 5. Collector-emitter on voltage vs temperature







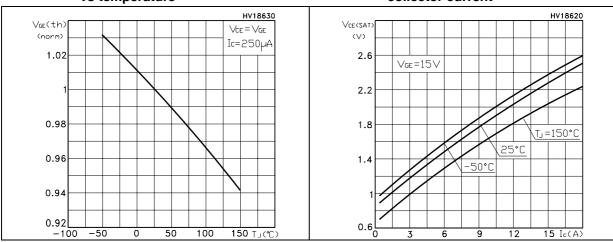


Figure 8. Normalized gate threshold voltage Figure 9. Collector-emitter on voltage vs collector current

Figure 10. Breakdown voltage vs temperature Figure 11.

e 11. Normalized collector-emitter on voltage vs temperature

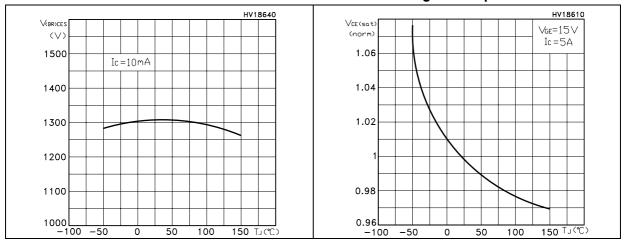
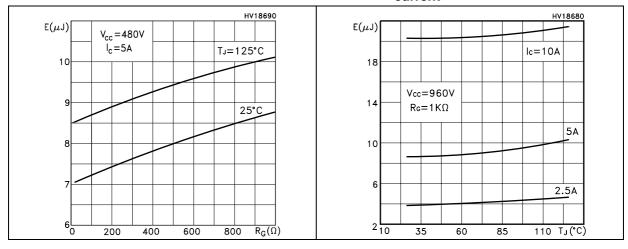


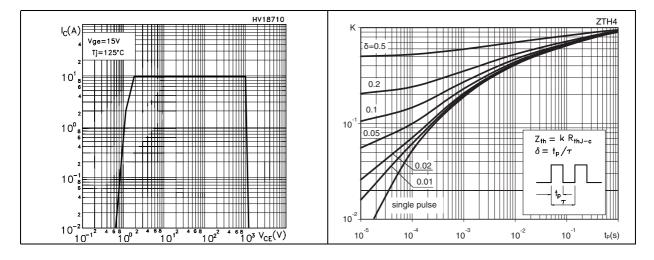
Figure 12. Switching losses vs gate resistance Figure 13. Switching losses vs collector current



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Figure 14. Turn-off SOA

Figure 15. Thermal impedance





3 Test circuit

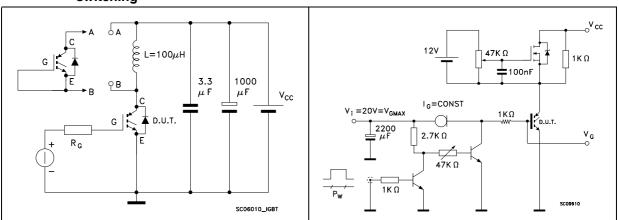
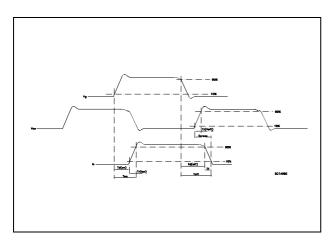


Figure 17. Gate charge test circuit

Figure 16. Test circuit for inductive load switching

Figure 18. Switching waveform





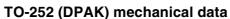
4 Package mechanical data

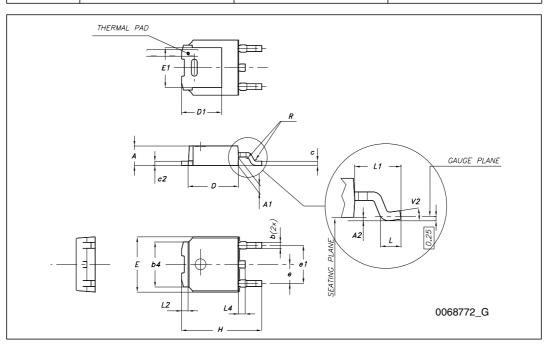
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: *www.st.com*

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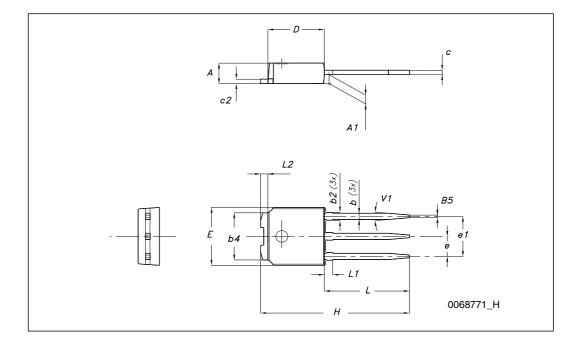
ом. —		mm.	
	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
с	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
e		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0 ^o		8 °



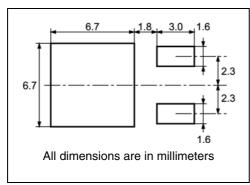


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	TO-251 (IPAK) mechanical data					
DIM.		mm.				
	min.	typ	max.			
A	2.20		2.40			
A1	0.90		1.10			
b	0.64		0.90			
b2			0.95			
b4	5.20		5.40			
с	0.45		0.60			
c2	0.48		0.60			
D	6.00		6.20			
E	6.40		6.60			
е		2.28				
e1	4.40		4.60			
н		16.10				
L	9.00		9.40			
(L1)	0.80		1.20			
L2		0.80				
V1		10 ^o				

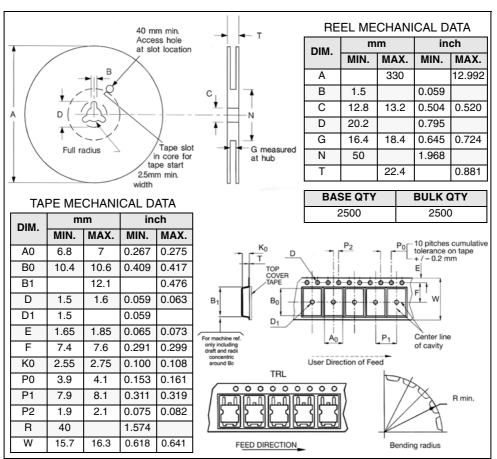


5 Packaging mechanical data



DPAK FOOTPRINT

TAPE AND REEL SHIPMENT



6 Revision history

Table 9. Document revision history

Date	Revision	Changes
06-Oct-2003	5	No history because migration
18-Jan-2005	6	Final datasheet
13-Nov-2008	7	Insert new value in Table 2: Absolute maximum ratings



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